

COMPLIANT

Standard Recovery Diodes (Stud Version), 400 A



PRODUCT SUMMARY			
I _{F(AV)}	400 A		
Package	DO-205AB (DO-9)		
Circuit configuration	Single diode		

FEATURES

- Wide current range
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC® types
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		400	А	
	T _C	120	°C	
I _{F(RMS)}		630	А	
I _{FSM}	50 Hz	8250	^	
	60 Hz	8640	A	
l ² t	50 Hz	340	kA ² s	
	60 Hz	311	KA-S	
V _{RRM}	Range	800 to 1600	V	
T _J		-40 to 200	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE VRRM, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA		
	80	800	900			
VS-400U(R)	120	1200	1300	15		
	160	1600	1700			



FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	1	180° conduction, half sine wave		400	Α	
at case temperature	I _{F(AV)}	180 Conduct	ion, nan sine wa	ve	120	°C
Maximum RMS forward current	I _{F(RMS)}	DC at 110 °C case temperature		re e	630	Α
		t = 10 ms	No voltage	Sinusoidal half wave, initial $T_J = T_J$ maximum	8250	A kA ² s
Maximum peak, one cycle forward, non-repetitive surge current		t = 8.3 ms	reapplied		8640	
	I _{FSM}	t = 10 ms	100 % V _{RRM}		6940	
		t = 8.3 ms	reapplied		7270	
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		340	
		t = 8.3 ms			311	
		t = 10 ms	100 % V _{RRM} reapplied		241	
		t = 8.3 ms			220	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		3400	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.77	.,	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.85	V	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.49	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.49	11152	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1500 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sinusoidal wave}$		1.62	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-40 to 200	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation		K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased		r √ vv
Maximum allowed mounting torque ± 10 %		Not lubricated threads	27	N⋅m
Approximate weight			250	g
Case style		See dimensions - link at the end of datasheet DO-205AB (DO-9		3 (DO-9)

△R _{th} JC CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.020	0.013				
120°	0.023	0.023				
90°	0.029	0.031	$T_J = T_J$ maximum	K/W		
60°	0.042	0.044				
30°	0.073	0.074				

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

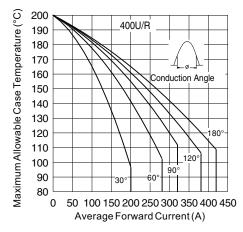


Fig. 1 - Current Ratings Characteristics

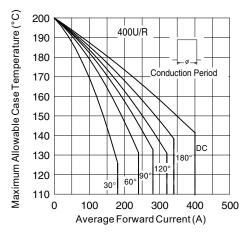


Fig. 2 - Current Ratings Characteristics

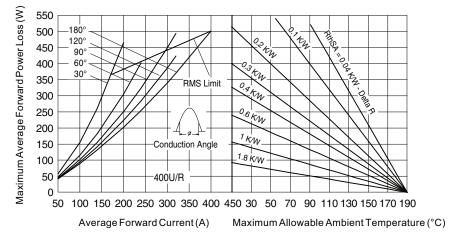


Fig. 3 - Forward Power Loss Characteristics

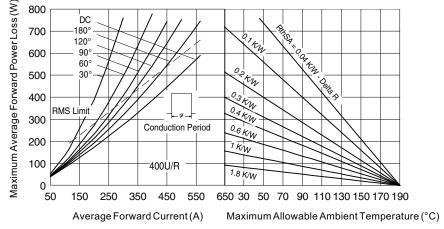


Fig. 4 - Forward Power Loss Characteristics

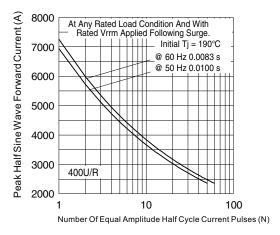


Fig. 5 - Maximum Non-Repetitive Surge Current

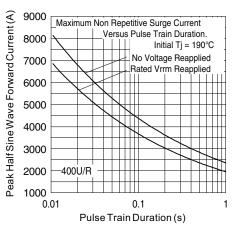


Fig. 6 - Maximum Non-Repetitive Surge Current

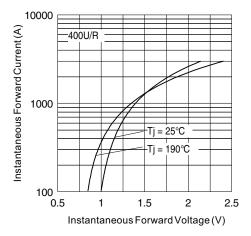


Fig. 7 - Forward Voltage Drop Characteristics

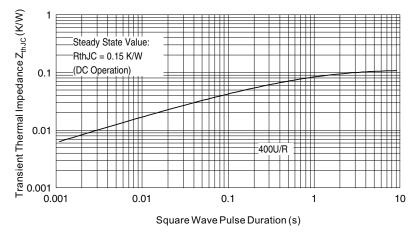
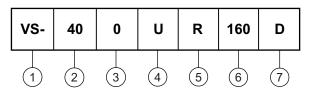


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - 40 = Essential part number

0 = Standard recovery device

U = Stud normal polarity (cathode to stud)

None = Stud normal polarity (cathode to stud)

• R = Stud reverse polarity (anode to stud)

6 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

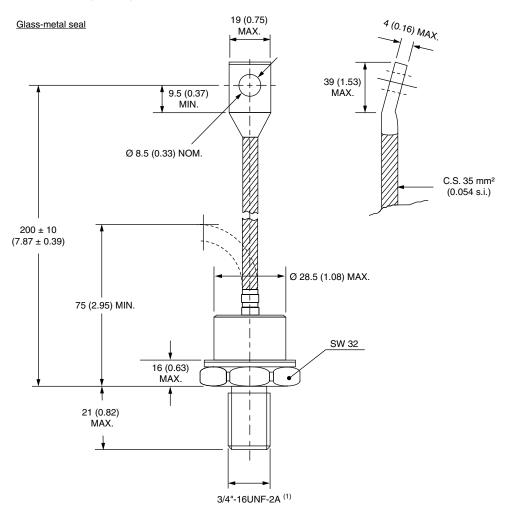
7 - Diffused diode

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95339		



DO-205AB (DO-9) for 400U(R) Series

DIMENSIONS in millimeters (inches)



Note

• For metric device: M16 x 1.5 contact factory

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